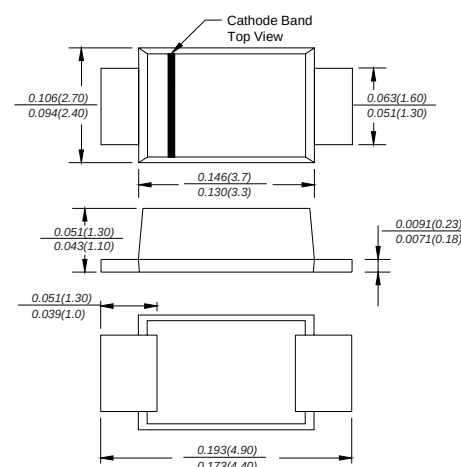


SS34F

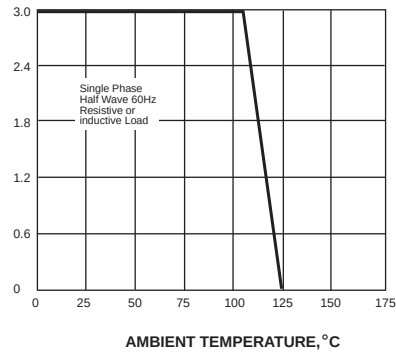
Surface Mount Schottky Barrier Rectifier

SMAF  Dimensions in inches and (millimeters)	FEATURES ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0 ◆ For surface mounted applications ◆ Metal silicon junction,majority carrier conduction ◆ Low power loss,high efficiency ◆ Built-in strain relief,ideal for automated placement ◆ High forward surge current capability ◆ High temperature soldering guaranteed: 260°C/10 seconds at terminals																																																
	MECHANICAL DATA Case: JEDEC SMAF molded plastic body Terminals: leads solderable per MIL-STD-750, Method 2026 Polarity: Color band denotes cathode end Mounting Position: Any Weight:0.0018 ounce, 0.064 grams																																																
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%. <table><tr><th>Catalog Number</th><th>SYMBOLS</th><th>SS34F</th><th>UNITS</th></tr><tr><td>Maximum repetitive peak reverse voltage</td><td>V_{RRM}</td><td>40</td><td>VOLTS</td></tr><tr><td>Maximum RMS voltage</td><td>V_{RMS}</td><td>28</td><td>VOLTS</td></tr><tr><td>Maximum DC blocking voltage</td><td>V_{DC}</td><td>40</td><td>VOLTS</td></tr><tr><td>Maximum average forward rectified current at T_L(see fig.1)</td><td>I_{AV}</td><td>2.8</td><td>Amp</td></tr><tr><td>Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)</td><td>I_{FSM}</td><td>80.0</td><td>Amps</td></tr><tr><td>Maximum instantaneous forward voltage at 3.0A</td><td>V_F</td><td>0.55</td><td>Volts</td></tr><tr><td>Maximum DC reverse current T_A=25°C at rated DC blocking voltage T_A=100°C</td><td>I_R</td><td>0.5 20.0</td><td>mA</td></tr><tr><td>Typical junction capacitance (NOTE 1)</td><td>C_J</td><td>500</td><td>pF</td></tr><tr><td>Typical thermal resistance (NOTE 2)</td><td>R_{θJA}</td><td>55.0</td><td>°C/W</td></tr><tr><td>Operating junction temperature range</td><td>T_J</td><td>-50 to +125</td><td>°C</td></tr><tr><td>Storage temperature range</td><td>T_{STG}</td><td>-50 to +150</td><td>°C</td></tr></table> Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C. 2.P.C.B. mounted with 0.2x0.2”(5.0x5.0mm) copper pad areas		Catalog Number	SYMBOLS	SS34F	UNITS	Maximum repetitive peak reverse voltage	V _{RRM}	40	VOLTS	Maximum RMS voltage	V _{RMS}	28	VOLTS	Maximum DC blocking voltage	V _{DC}	40	VOLTS	Maximum average forward rectified current at T _L (see fig.1)	I _{AV}	2.8	Amp	Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	80.0	Amps	Maximum instantaneous forward voltage at 3.0A	V _F	0.55	Volts	Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =100°C	I _R	0.5 20.0	mA	Typical junction capacitance (NOTE 1)	C _J	500	pF	Typical thermal resistance (NOTE 2)	R _{θJA}	55.0	°C/W	Operating junction temperature range	T _J	-50 to +125	°C	Storage temperature range	T _{STG}	-50 to +150	°C
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RATINGS AND CHARACTERISTIC CURVES

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

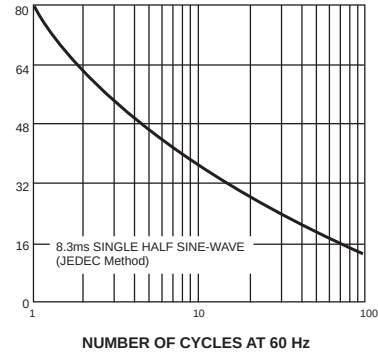


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

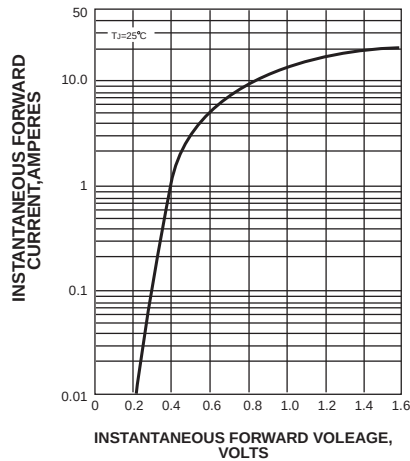


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

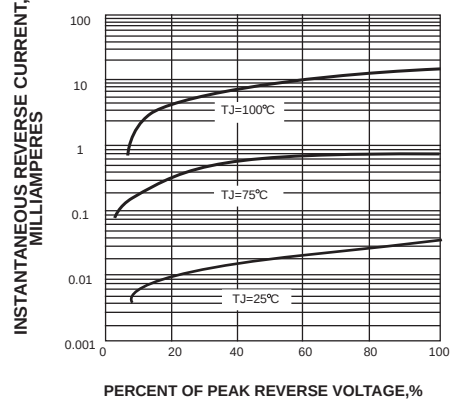
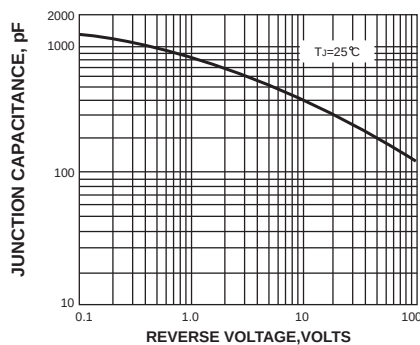
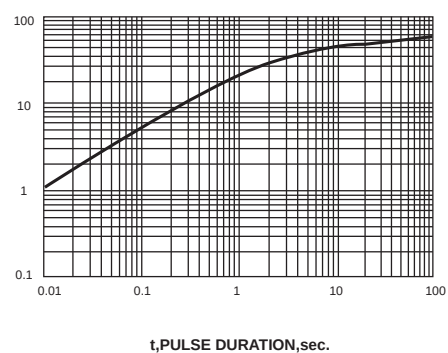


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!